

TOSHIBA CMOS Digital Integrated Circuit Silicon Monolithic

TC74VCXH16244FT

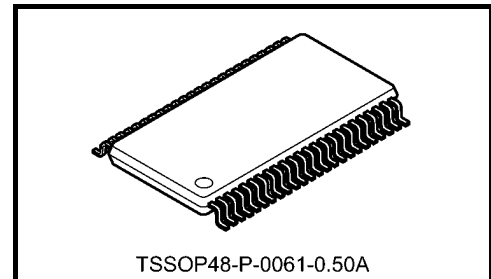
Low-Voltage 16-Bit Bus Buffer with Bushold

The TC74VCXH16244FT is a high-performance CMOS 16-bit bus buffer. Designed for use in 1.8-V, 2.5-V or 3.3-V systems, it achieves high-speed operation while maintaining the CMOS low power dissipation.

This device is non-inverting 3-state buffer having four active-low output enables. It can be used as four 4-bit buffers two 8-bit buffers or one 16-bit buffer. When the \overline{OE} input is high, the outputs are in a high-impedance state. This device is designed to be used with 3-state memory address drivers, etc.

The A data inputs include active bushold circuitry, eliminating the need for external pull-up resistors to hold unused or floating data inputs at a valid logic level.

All inputs are equipped with protection circuits against static discharge.

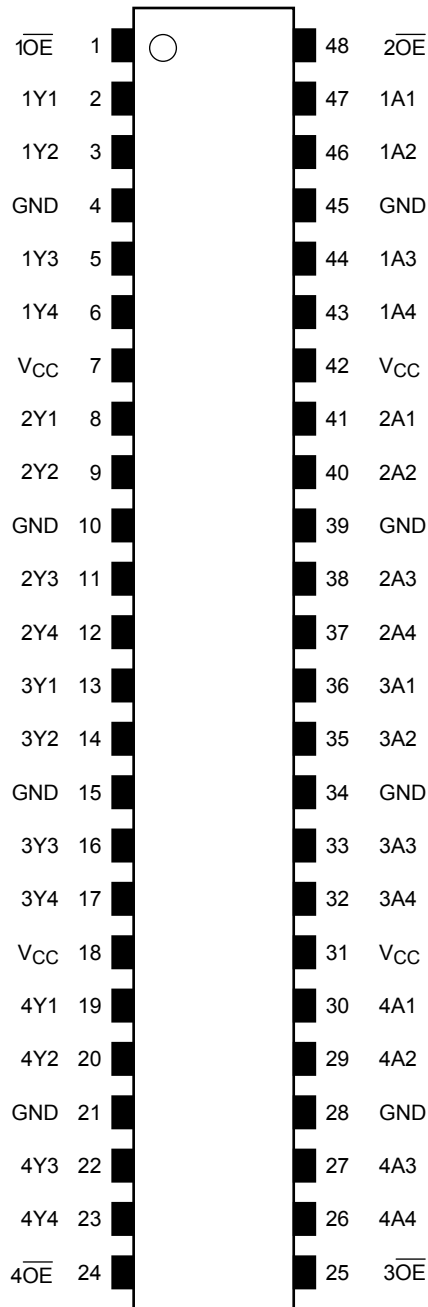


Weight: 0.25 g (typ.)

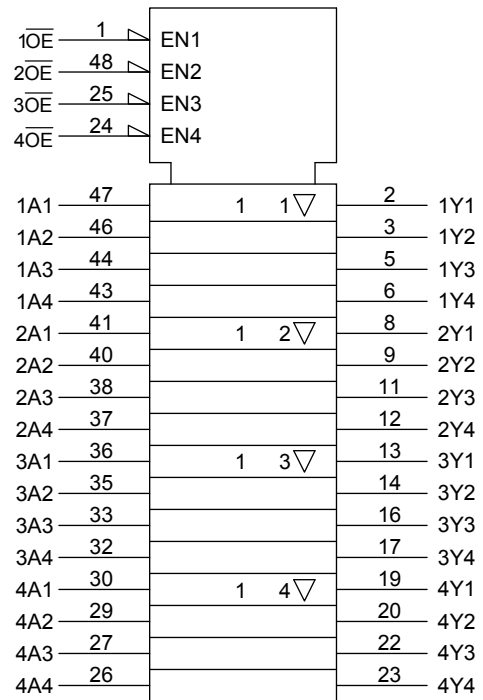
Features

- Low-voltage operation: $V_{CC} = 1.8$ to 3.6 V
- Bushold on data inputs eliminating the need for external pull-up/pull-down resistors
- High-speed operation: $t_{pd} = 2.5$ ns (max) ($V_{CC} = 3.0$ to 3.6 V)
: $t_{pd} = 3.0$ ns (max) ($V_{CC} = 2.3$ to 2.7 V)
: $t_{pd} = 5.0$ ns (max) ($V_{CC} = 1.8$ V)
- Output current: $I_{OH}/I_{OL} = \pm 24$ mA (min) ($V_{CC} = 3.0$ V)
: $I_{OH}/I_{OL} = \pm 18$ mA (min) ($V_{CC} = 2.3$ V)
: $I_{OH}/I_{OL} = \pm 6$ mA (min) ($V_{CC} = 1.8$ V)
- Latch-up performance: -300 mA
- ESD performance: Machine model $\geq \pm 200$ V
Human body model $\geq \pm 2000$ V
- Package: TSSOP
- 3.6-V tolerant function and power-down protection control inputs and outputs

Pin Assignment (top view)



IEC Logic Symbol



Truth Table

Inputs		Outputs
$\overline{1OE}$	1A1-1A4	1Y1-1Y4
L	L	L
L	H	H
H	X	Z

Inputs		Outputs
$\overline{2OE}$	2A1-2A4	2Y1-2Y4
L	L	L
L	H	H
H	X	Z

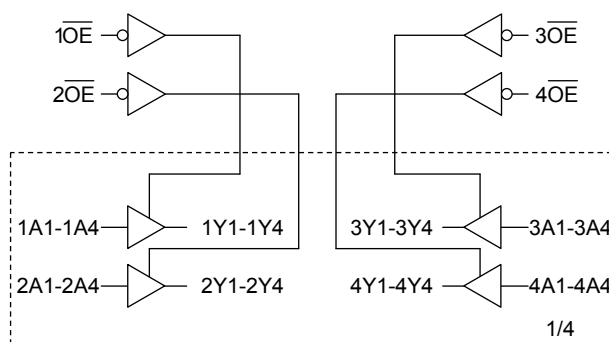
Inputs		Outputs
$\overline{3OE}$	3A1-3A4	3Y1-3Y4
L	L	L
L	H	H
H	X	Z

Inputs		Outputs
$\overline{4OE}$	4A1-4A4	4Y1-4Y4
L	L	L
L	H	H
H	X	Z

X: Don't care

Z: High impedance

System Diagram



Absolute Maximum Ratings (Note 1)

Characteristics	Symbol	Rating	Unit
Power supply voltage	V_{CC}	-0.5 to 4.6	V
DC input voltage	(\overline{OE})	-0.5 to 4.6	V
	(An)	-0.5 to $V_{CC} + 0.5$	
DC output voltage	V_{OUT}	-0.5 to 4.6 (Note 2)	V
		-0.5 to $V_{CC} + 0.5$ (Note 3)	
Input diode current	I_{IK}	-50	mA
Output diode current	I_{OK}	± 50 (Note 4)	mA
Output current	I_{OUT}	± 50	mA
Power dissipation	P_D	400	mW
DC V_{CC} /ground current per supply pin	I_{CC}/I_{GND}	± 100	mA
Storage temperature	T_{stg}	-65 to 150	$^{\circ}C$

Note 1: Exceeding any of the absolute maximum ratings, even briefly, lead to deterioration in IC performance or even destruction.

Using continuously under heavy loads (e.g. the application of high temperature/current/voltage and the significant change in temperature, etc.) may cause this product to decrease in the reliability significantly even if the operating conditions (i.e. operating temperature/current/voltage, etc.) are within the absolute maximum ratings and the operating ranges.

Please design the appropriate reliability upon reviewing the Toshiba Semiconductor Reliability Handbook ("Handling Precautions"/"Derating Concept and Methods") and individual reliability data (i.e. reliability test report and estimated failure rate, etc).

Note 2: OFF state

Note 3: High or low state. I_{OUT} absolute maximum rating must be observed.

Note 4: $V_{OUT} < GND$, $V_{OUT} > V_{CC}$

Operating Ranges (Note 1) (Note 2)

Characteristics		Symbol	Rating	Unit
Power supply voltage		V_{CC}	1.8 to 3.6	V
			1.2 to 3.6 (Note 3)	
Input voltage	(\overline{OE})	V_{IN}	-0.3 to 3.6	V
	(An)		0 to V_{CC}	
Output voltage		V_{OUT}	0 to 3.6 (Note 4)	V
			0 to V_{CC} (Note 5)	
Output current		I_{OH}/I_{OL}	± 24 (Note 6)	mA
			± 18 (Note 7)	
			± 6 (Note 8)	
Operating temperature		T_{opr}	-40 to 85	$^{\circ}C$
Input rise and fall time		dt/dv	0 to 10 (Note 9)	ns/V

Note 1: The operating ranges must be maintained to ensure the normal operation of the device.
Unused inputs must be tied to either VCC or GND.

Note 2: Floating or unused control inputs must be held high or low.

Note 3: Data retention

Note 4: OFF state

Note 5: High or low state

Note 6: $V_{CC} = 3.0$ to 3.6 V

Note 7: $V_{CC} = 2.3$ to 2.7 V

Note 8: $V_{CC} = 1.8$ V

Note 9: $V_{IN} = 0.8$ to 2.0 V, $V_{CC} = 3.0$ V

Electrical Characteristics

DC Characteristics (Ta = -40 to 85°C, 2.7 V < V_{CC} ≤ 3.6 V)

Characteristics		Symbol	Test Condition	V _{CC} (V)	Min	Max	Unit
Input voltage	H-level	V _{IH}	—	2.7 to 3.6	2.0	—	V
	L-level	V _{IL}	—	2.7 to 3.6	—	0.8	
Output voltage	H-level	V _{OH}	V _{IN} = V _{IH} or V _{IL}	I _{OH} = -100 μA	2.7 to 3.6	V _{CC} - 0.2	V
				I _{OH} = -12 mA	2.7	2.2	
				I _{OH} = -18 mA	3.0	2.4	
				I _{OH} = -24 mA	3.0	2.2	
	L-level	V _{OL}	V _{IN} = V _{IH} or V _{IL}	I _{OL} = 100 μA	2.7 to 3.6	—	0.2
				I _{OL} = 12 mA	2.7	—	0.4
				I _{OL} = 18 mA	3.0	—	0.4
				I _{OL} = 24 mA	3.0	—	0.55
Input leakage current	(\overline{OE})	I _{IN}	V _{IN} = 0 to 3.6 V	2.7 to 3.6	—	±5.0	μA
	(An)		V _{IN} = V _{CC} or GND	2.7 to 3.6	—	±5.0	
Bushold input minimum drive hold current	I _I (HOLD)	V _{IN} = 0.8 V	3.0	75	—	μA	
		V _{IN} = 2.0 V	3.0	-75	—		
Bushold input over-drive current to change state	I _I (OD)	(Note 1)	3.6	—	450	μA	
		(Note 2)	3.6	—	-450		
3-state output OFF state current	I _{OZ}	V _{IN} = V _{IH} or V _{IL} V _{OUT} = 0 to 3.6 V	2.7 to 3.6	—	±10.0	μA	
Power-off leakage current	I _{OFF}	V _{OUT} = 0 to 3.6 V	0	—	10.0	μA	
Quiescent supply current	I _{CC}	V _{IN} = V _{CC} or GND	2.7 to 3.6	—	20.0	μA	
		V _{CC} ≤ V _{OUT} ≤ 3.6 V (Note 3)	2.7 to 3.6	—	±20.0		
Increase in I _{CC} per input	ΔI _{CC}	V _{IH} = V _{CC} - 0.6 V	2.7 to 3.6	—	750	μA	

Note 1: An external driver must source at least the specified current to switch LOW-to-HIGH.

Note 2: An external driver must sink at least the specified current to switch HIGH-to-LOW.

Note 3: Outputs high impedance only.

DC Characteristics (Ta = -40 to 85°C, 2.3 V ≤ VCC ≤ 2.7 V)

Characteristics		Symbol	Test Condition		VCC (V)	Min	Max	Unit
Input voltage	H-level	V _{IH}	—		2.3 to 2.7	1.6	—	V
	L-level	V _{IL}	—		2.3 to 2.7	—	0.7	
Output voltage	H-level	V _{OH}	V _{IN} = V _{IH} or V _{IL}	I _{OH} = -100 μA	2.3 to 2.7	V _{CC} - 0.2	—	V
				I _{OH} = -6 mA	2.3	2.0	—	
				I _{OH} = -12 mA	2.3	1.8	—	
	L-level	V _{OL}	V _{IN} = V _{IH} or V _{IL}	I _{OL} = 100 μA	2.3 to 2.7	—	0.2	
				I _{OL} = 12 mA	2.3	—	0.4	
				I _{OL} = 18 mA	2.3	—	0.6	
Input leakage current	(\overline{OE})	I _{IN}	V _{IN} = 0 to 3.6 V	2.3 to 2.7	—	±5.0	μA	
	(An)		V _{IN} = V _{CC} or GND	2.3 to 2.7	—	±5.0		
Bushold input minimum drive hold current		I _I (HOLD)	V _{IN} = 0.7 V	2.3	45	—	μA	
			V _{IN} = 1.6 V	2.3	-45	—		
Bushold input over-drive current to change state		I _I (OD)	(Note 1)	2.7	—	300	μA	
			(Note 2)	2.7	—	-300		
3-state output OFF state current		I _{OZ}	V _{IN} = V _{IH} or V _{IL} V _{OUT} = 0 to 3.6 V	2.3 to 2.7	—	±10.0	μA	
Power-off leakage current		I _{OFF}	V _{OUT} = 0 to 3.6 V	0	—	10.0	μA	
Quiescent supply current		I _{CC}	V _{IN} = V _{CC} or GND	2.3 to 2.7	—	20.0	μA	
			V _{CC} ≤ V _{OUT} ≤ 3.6 V (Note 3)	2.3 to 2.7	—	±20.0		

Note 1: An external driver must source at least the specified current to switch LOW-to-HIGH.

Note 2: An external driver must sink at least the specified current to switch HIGH-to-LOW.

Note 3: Outputs high impedance only.

DC Characteristics (Ta = -40 to 85°C, 1.8 V ≤ VCC < 2.3 V)

Characteristics		Symbol	Test Condition		VCC (V)	Min	Max	Unit
Input voltage	H-level	V _{IH}	—		1.8 to 2.3	0.7 × V _{CC}	—	V
	L-level	V _{IL}	—		1.8 to 2.3	—	0.2 × V _{CC}	
Output voltage	H-level	V _{OH}	V _{IN} = V _{IH} or V _{IL}	I _{OH} = -100 μA	1.8	V _{CC} - 0.2	—	V
				I _{OH} = -6 mA	1.8	1.4	—	
	L-level	V _{OL}	V _{IN} = V _{IH} or V _{IL}	I _{OL} = 100 μA	1.8	—	0.2	
				I _{OL} = 6 mA	1.8	—	0.3	
Input leakage current	(\overline{OE})	I _{IN}	V _{IN} = 0 to 3.6 V		1.8	—	±5.0	μA
	(An)		V _{IN} = V _{CC} or GND		1.8	—	±5.0	
Bushold input minimum drive hold current	I _I (HOLD)	V _{IN} = 0.36 V		1.8	25	—	μA	
		V _{IN} = 1.26 V		1.8	-25	—		
Bushold input over-drive current to change state	I _I (OD)	(Note 1)		1.8	—	200	μA	
		(Note 2)		1.8	—	-200		
3-state output OFF state current	I _{OZ}	V _{IN} = V _{IH} or V _{IL} V _{OUT} = 0 to 3.6 V		1.8	—	±10.0	μA	
Power-off leakage current	I _{OFF}	V _{OUT} = 0 to 3.6 V		0	—	10.0	μA	
Quiescent supply current	I _{CC}	V _{IN} = V _{CC} or GND		1.8	—	20.0	μA	
		V _{CC} ≤ V _{OUT} ≤ 3.6 V (Note 3)		1.8	—	±20.0		

Note 1: An external driver must source at least the specified current to switch LOW-to-HIGH.

Note 2: An external driver must sink at least the specified current to switch HIGH-to-LOW.

Note 3: Outputs high impedance only.

AC Characteristics (Ta = -40 to 85°C, input: t_r = t_f = 2.0 ns, C_L = 30 pF, R_L = 500 Ω) (Note 1)

Characteristics		Symbol	Test Condition		VCC (V)	Min	Max	Unit
Propagation delay time	t _{pLH} t _{pHL}	Figure 1, Figure 2	1.8	1.5	5.0	ns		
			2.5 ± 0.2	1.0	3.0			
			3.3 ± 0.3	0.8	2.5			
3-state output enable time	t _{pZL} t _{pZH}	Figure 1, Figure 3	1.8	1.5	6.5	ns		
			2.5 ± 0.2	1.0	4.1			
			3.3 ± 0.3	0.8	3.5			
3-state output disable time	t _{pLZ} t _{pHZ}	Figure 1, Figure 3	1.8	1.5	5.0	ns		
			2.5 ± 0.2	1.0	3.8			
			3.3 ± 0.3	0.8	3.5			
Output to output skew	t _{osLH} t _{osHL}	(Note 2)	1.8	—	0.5	ns		
			2.5 ± 0.2	—	0.5			
			3.3 ± 0.3	—	0.5			

Note 1: For C_L = 50 pF, add approximately 300 ps to the AC maximum specification.

Note 2: Parameter guaranteed by design.

$$(t_{osLH} = |t_{pLHm} - t_{pLHn}|; t_{osHL} = |t_{pHLm} - t_{pHLn}|)$$

Dynamic Switching Characteristics (Ta = 25°C, input: tr = tf = 2.0 ns, CL = 30 pF)

Characteristics	Symbol	Test Condition	VCC (V)	Typ.	Unit
Quiet output maximum dynamic VOL	VOLP	VIH = 1.8 V, VIL = 0 V (Note)	1.8	0.25	V
		VIH = 2.5 V, VIL = 0 V (Note)	2.5	0.6	
		VIH = 3.3 V, VIL = 0 V (Note)	3.3	0.8	
Quiet output minimum dynamic VOL	VOLV	VIH = 1.8 V, VIL = 0 V (Note)	1.8	-0.25	V
		VIH = 2.5 V, VIL = 0 V (Note)	2.5	-0.6	
		VIH = 3.3 V, VIL = 0 V (Note)	3.3	-0.8	
Quiet output minimum dynamic VOH	VOHV	VIH = 1.8 V, VIL = 0 V (Note)	1.8	1.5	V
		VIH = 2.5 V, VIL = 0 V (Note)	2.5	1.9	
		VIH = 3.3 V, VIL = 0 V (Note)	3.3	2.2	

Note: Parameter guaranteed by design.

Capacitive Characteristics (Ta = 25°C)

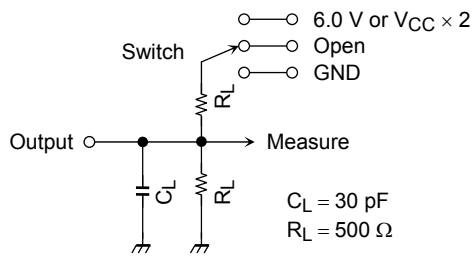
Characteristics	Symbol	Test Condition	VCC (V)	Typ.	Unit
Input capacitance	CIN	—	1.8, 2.5, 3.3	6	pF
Output capacitance	CO	—	1.8, 2.5, 3.3	7	pF
Power dissipation capacitance	CPD	fIN = 10 MHz (Note)	1.8, 2.5, 3.3	20	pF

Note: CPD is defined as the value of the internal equivalent capacitance which is calculated from the operating current consumption without load.

Average operating current can be obtained by the equation:

$$I_{CC (opr)} = C_{PD} \cdot V_{CC} \cdot f_{IN} + I_{CC}/16 \text{ (per bit)}$$

AC Test Circuit



Parameter	Switch
t_{pLH}, t_{pHL}	Open
t_{pLZ}, t_{pZL}	6.0 V $V_{CC} \times 2$ @ $V_{CC} = 3.3 \pm 0.3 \text{ V}$ @ $V_{CC} = 2.5 \pm 0.2 \text{ V}$ @ $V_{CC} = 1.8 \text{ V}$
t_{pHZ}, t_{pZH}	GND

Figure 1

AC Waveform

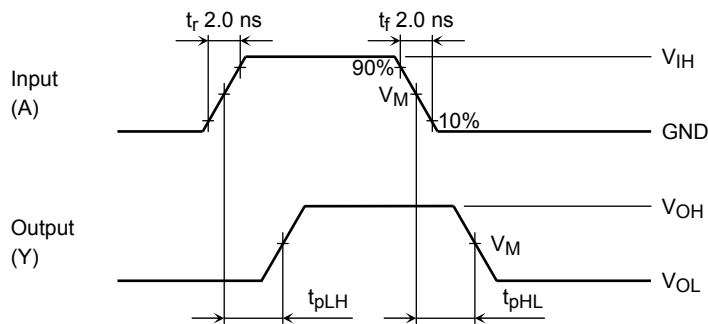


Figure 2 t_{pLH}, t_{pHL}

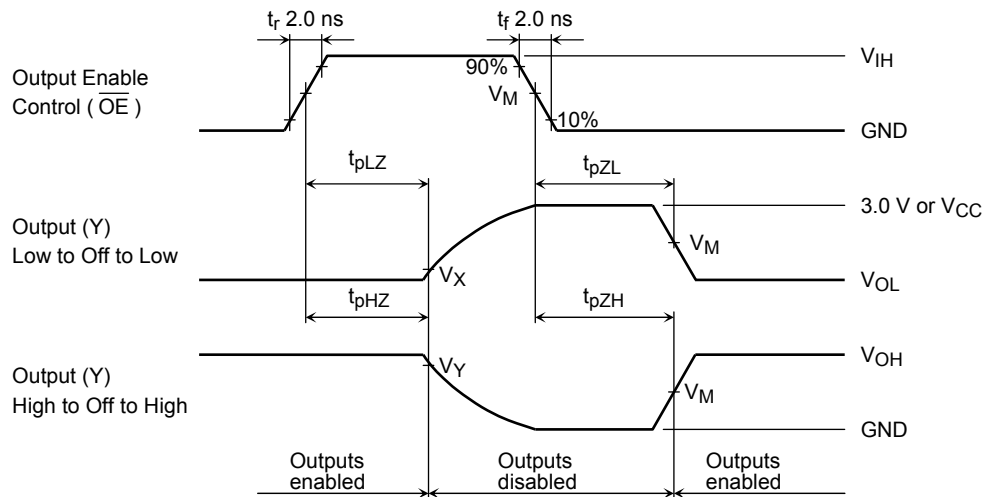


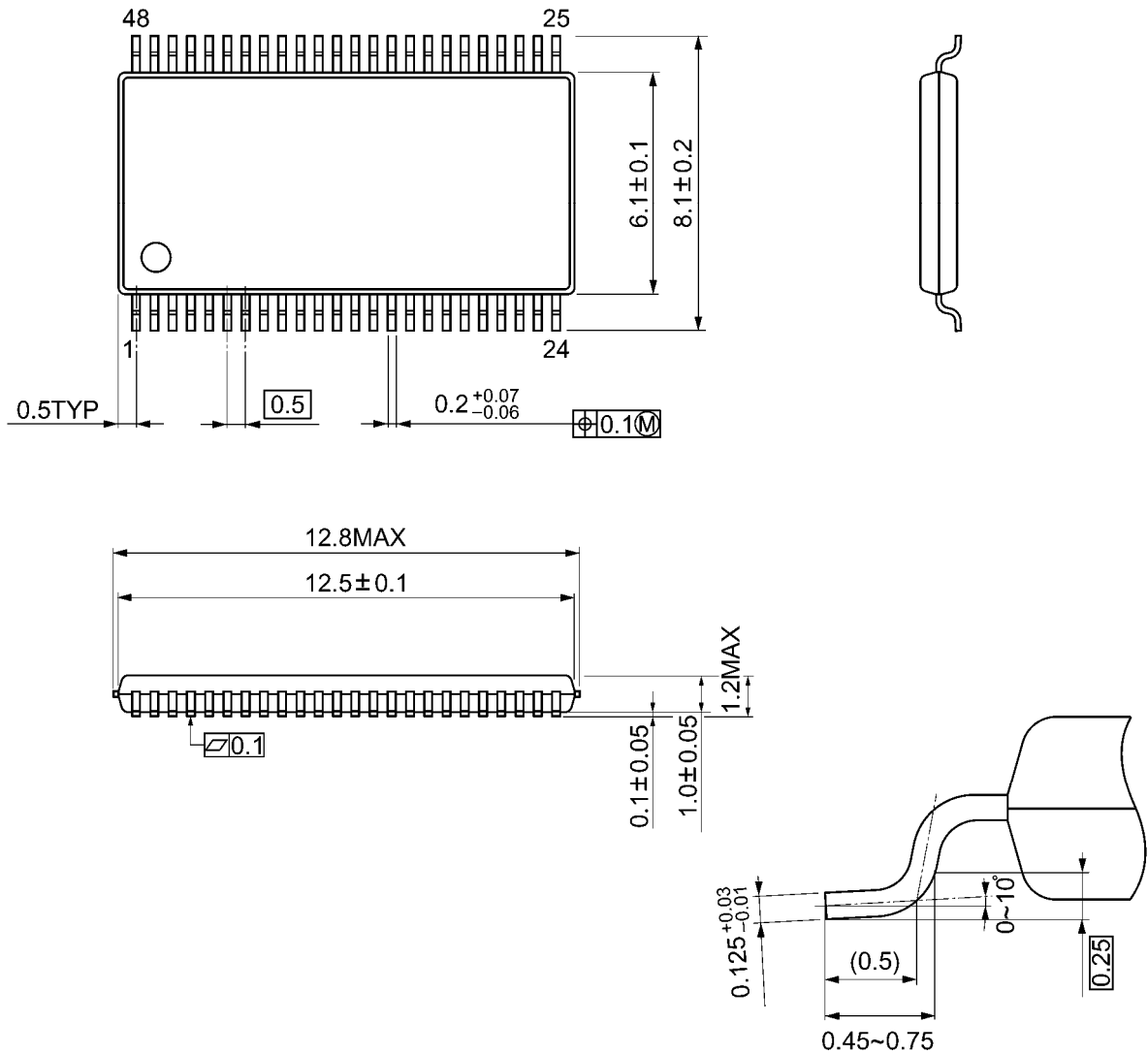
Figure 3 $t_{pLZ}, t_{pHZ}, t_{pZL}, t_{pZH}$

Symbol	V_{CC}		
	$3.3 \pm 0.3 \text{ V}$	$2.5 \pm 0.2 \text{ V}$	1.8 V
V_{IH}	2.7 V	V_{CC}	V_{CC}
V_M	1.5 V	$V_{CC}/2$	$V_{CC}/2$
V_X	$V_{OL} + 0.3 \text{ V}$	$V_{OL} + 0.15 \text{ V}$	$V_{OL} + 0.15 \text{ V}$
V_Y	$V_{OH} - 0.3 \text{ V}$	$V_{OH} - 0.15 \text{ V}$	$V_{OH} - 0.15 \text{ V}$

Package Dimensions

TSSOP48-P-0061-0.50A

Unit: mm



Weight: 0.25 g (typ.)

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20070701-EN GENERAL

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